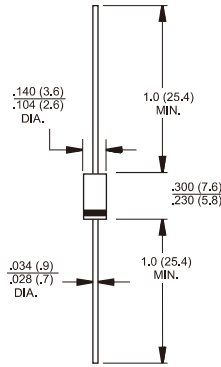


Features

- ✧ Glass passivated chip junction.
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, Lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode end
- ✧ High temperature soldering guaranteed: 260 °C /10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Weight: 0.40 grams



Dimensions in inches and (millimeters)

Marking Diagram



- FR15XG = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	FR	FR	FR	FR	FR	FR	FR	Units
		151G	152G	153G	154G	155G	156G	157G	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length @ $T_A = 55^\circ C$	$I_{F(AV)}$	1.5							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage @ 1.5A	V_F	1.3							V
Maximum DC Reverse Current at @ $T_A=25^\circ C$ Rated DC Blocking Voltage (Note 1) @ $T_A=125^\circ C$	I_R	5.0 100							μA μA
Maximum Reverse Recovery Time (Note 4)	T_{rr}	150			250	500		nS	
Typical Junction Capacitance (Note 2)	C_j	20							pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$	60							$^\circ C/W$
Operating Temperature Range	T_J	-65 to +150							$^\circ C$
Storage Temperature Range	T_{STG}	-65 to +150							$^\circ C$

- Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.
 3. Mount on Cu-Pad Size 10mm x 10mm on P.C.B.
 4. Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$

RATINGS AND CHARACTERISTIC CURVES (FR151G THRU FR157G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

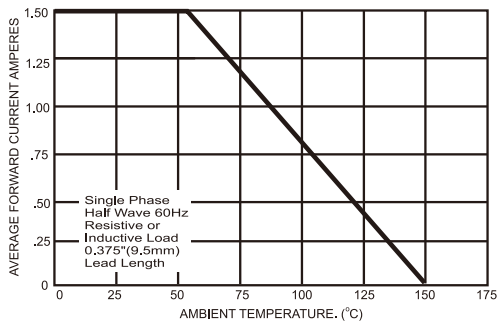


FIG.2- TYPICAL REVERSE CHARACTERISTICS PER LEG

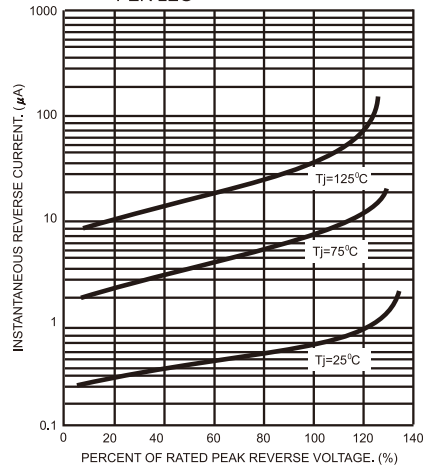


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

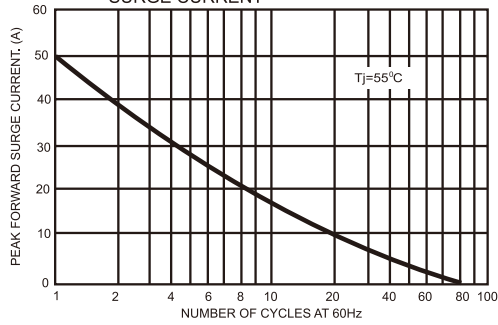


FIG.5- TYPICAL FORWARD CHARACTERISTICS

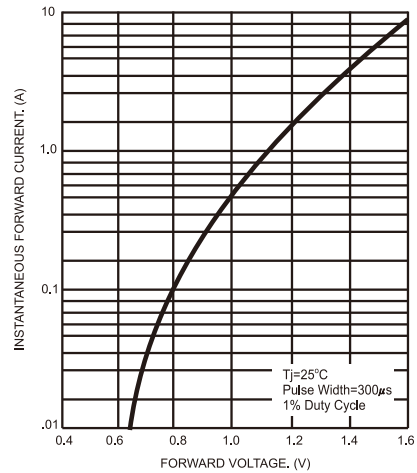


FIG.4- TYPICAL JUNCTION CAPACITANCE

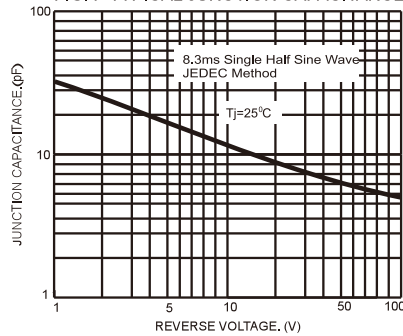


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

